

Ultra-Low On-Resistance, 4-A Integrated Load Switch with Controlled Turn-on

Check for Samples: TPS22920

FEATURES

- Integrated Load Switch
- Input Voltage Range: 0.75-V to 3.6-V
- Integrated Pass-FET r_{DSON} = 2mΩ (typ) at 3.6-V
- Ultra-Low ON-Resistance
 - $r_{ON} = 5.3 m\Omega$ at 3.6-V
 - $r_{ON} = 5.4-m\Omega$ at 2.5-V
 - r_{ON} = 5.5-mΩ at 1.8-V
 - $r_{ON} = 5.8 m\Omega$ at 1.2-V
 - $r_{ON} = 6.1 m\Omega$ at 1.05-V
 - $r_{ON} = 7.3 m\Omega$ at 0.75-V
- Ultra Small CSP-8 package 0.9mm×1.9mm, 0.5mm pitch
- 4-A Maximum Continuous Switch Current
- Shutdown Current 5.5-µA max
- Low Threshold Control Input
- · Controlled slew- rate to avoid inrush current
- Quick Output Discharge Transistor
- ESD Performance Tested Per JESD 22
 - 4000-V Human-Body Model (A114-B, Class II)
 - 1000-V Charged-Device Model (C101)

APPLICATIONS

- Notebook / Netbook Computer
- Tablet PC
- PDAs / Smartphones
- GPS Navigation Devices
- MP3 Players

DESCRIPTION

The TPS22920 is a small, ultra-low r_{ON} load switch with controlled turn on. The device contains a N-channel MOSFET that can operate over an input voltage range of 0.75 V to 3.6 V and switch currents up to 4-A. An integrated charge pump biases the NMOS switch in order to achieve a minimum switch ON resistance (r_{ON}) . The switch is controlled by an on/off input (ON), which is capable of interfacing directly with low-voltage control signals.

The TPS22920 has a $1250-\Omega$ on-chip load resistor for quick output discharge when the switch is turned off.

The TPS22920 has an internally controlled rise time in order to reduce inrush current. The TPS22920 features a rise time of 880µS at 3.6-V.

The TPS22920 is available in an ultra-small, spacesaving 8-pin CSP package and is characterized for operation over the free-air temperature range of -40°C to 85°C.

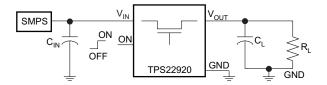


Figure 1. Typical Application

FEATURE LIST

	r _{ON} (typ) at 3.6 V	RISE TIME (typ) at 3.6V	QUICK OUTPUT DISCHARGE ⁽¹⁾	MAXIMUM OUTPUT CURRENT	ENABLE	
TPS22920	5.3- mΩ	880 µS	Yes	4-A	Active High	

(1) This feature discharges the output of the switch to ground through a 1250-Ω resistor, preventing the output from floating. See Application section 'Output Pull-Down'



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.





This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

Figure 2. Bump Assignments

Bump Assignments (YZP Package)

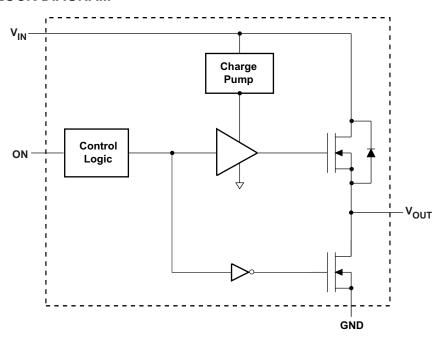
•	•	U ,
D	GND	ON
С	V _{OUT}	V _{IN}
В	V _{OUT}	V _{IN}
Α	V _{OUT}	V _{IN}
	1	2

Pin Description

TPS22920	PIN NAME	DESCRIPTION				
YZP	PIN NAME	DESCRIPTION				
D1	GND	Ground				
D2	ON	Switch control input, active high. Do not leave floating				
A1, B1, C1	VOUT	Switch output				
A2, B2, C2	VIN	Switch input, bypass this input with a ceramic capacitor to ground				



FUNCTIONAL BLOCK DIAGRAM



FUNCTION TABLE

ON	VIN to VOUT	VOUT to GND ⁽¹⁾		
L	OFF	ON		
Н	ON	OFF		

(1) See Application section 'Output Pull-Down'

ABSOLUTE MAXIMUM RATINGS(1)

			VALUE	UNIT	
V _{IN}	Input voltage range		-0.3 to 4	V	
V_{OUT}	Output voltage range		VIN + 0.3	V	
V_{ON}	Input voltage range		-0.3 to 4	V	
I_{MAX}	Maximum Continuous Switch Curre	4	Α		
I _{PLS}	Maximum Pulsed Switch Current, po	6	Α		
T _A	Operating free-air temperature rang	-40 to 85	°C		
T_J	Maximum junction temperature		125	°C	
T _{STG}	Storage temperature range		-65 to 150	°C	
T_{LEAD}	Maximum lead temperature (10-s so	300	°C		
ECD.		Human-Body Model (HBM)	4000		
ESD	Electrostatic discharge protection	Charged Device Model (CDM)	1000	V	

(1) Stresses beyond those listed under absolute maximum ratings may cause permanent damage to the device. These are stress only, and functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.



THERMAL INFORMATION

	THERMAL METRIC ⁽¹⁾	TPS22920	LINUTO
	I HERMAL METRIC"	CS130P (8 PINS)	UNITS
θ_{JA}	Junction-to-ambient thermal resistance	130	
θ_{JCtop}	Junction-to-case (top) thermal resistance	54	
θ_{JB}	Junction-to-board thermal resistance	51	°C/W
ΨЈТ	Junction-to-top characterization parameter	1	C/VV
ΨЈВ	Junction-to-board characterization parameter	50	
θ_{JCbot}	Junction-to-case (bottom) thermal resistance	n/a	

⁽¹⁾ For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics application report, SPRA953.

RECOMMENDED OPERATING CONDITIONS

			MIN	MAX	UNIT
V_{IN}	Input voltage range		0.75	3.6	V
V_{OUT}	Output voltage range		V_{IN}	V	
V	High-level input voltage, ON	$V_{IN} = 2.5 - V \text{ to } 3.6 \text{ V}$	1.2	3.6	V
V _{IH}		$V_{IN} = 0.75 - V \text{ to } 2.49 \text{ V}$	0.9	3.6	V
V	Law law line of walks are ON	$V_{IN} = 2.5 - V \text{ to } 3.6 \text{ V}$		0.6	V
V _{IL}	Low-level input voltage, ON	$V_{IN} = 0.75 - V \text{ to } 2.49 \text{ V}$		0.4	V
C _{IN}	Input Capacitor		1 ⁽¹⁾		μF

⁽¹⁾ See Input Capacitor section in Application Information.

ELECTRICAL CHARACTERISTICS

 $V_{IN} = 0.75 \text{ V}$ to 3.6 V (unless otherwise noted)

PARAMETER		TEST C	ONDITIONS	T _A	MIN TYP ⁽¹⁾	MAX	UNIT
			V _{IN} = 3.6 V		68	160	
			V _{IN} = 2.5 V		40	70	μΑ
	Ouiseant Current		V _{IN} = 1.8 V	F	25	350	
I _{IN}	Quiescent Current	$I_{OUT} = 0$, $V_{IN} = V_{ON}$	V _{IN} = 1.2 V	Full	103	200	μA
			V _{IN} = 1.05 V		78	110	
			V _{IN} = 0.75 V		37	70	μA
I _{IN(leak)}	Off Supply Current (After Pull Down)	$V_{ON} = GND, V_{OUT} =$	0	Full		5.5	μΑ
		V _{IN} = 3.6 V, I _{OUT} = -200 mA		25°C	5.3	8.8	mΩ
				Full		9.8	
		V _{IN} = 2.5 V, I _{OUT} = -200 mA		25°C	5.4	8.9	mΩ
				Full		9.9	
		V _{IN} = 1.8 V, I _{OUT} = -200 mA		25°C	5.5	9.1	mΩ mΩ
_	On Registance			Full		10.1	
r _{ON}	On-Resistance	V _{IN} = 1.2 V, I _{OUT} = -200 mA		25°C	5.8	9.4	
				Full		10.4	11122
		\/ 4.05.\/ I	200 4	25°C	6.1	9.7	mΩ
		V _{IN} = 1.05 V, I _{OUT} =	-200 MA	Full		10.8	11177
		\/ - 0.75 \/ l -	200 m A	25°C	7.3	11.0	
		$V_{IN} = 0.75 \text{ V}, I_{OUT} = -200 \text{ mA}$		Full		12.4	mΩ
RPD	Output pull down resistance (2)	$V_{IN} = 3.3 \text{ V}, V_{ON} = 0$), I _{OUT} = 3 mA	Full	1250	1500	Ω
I _{ON}	ON input leakage current	$V_{ON} = 0.9 \text{ V to } 3.6 \text{ V}$	or GND	Full		0.1	μΑ

Typical values are at $V_{\rm IN}$ = 3.3 V and $T_{\rm A}$ = 25°C. See Output Pulldown in *Application Information*.



SWITCHING CHARACTERISTICS

 $V_{IN} = 3.6 \text{ V}, T_A = 25^{\circ}\text{C} \text{ (unless otherwise noted)}$

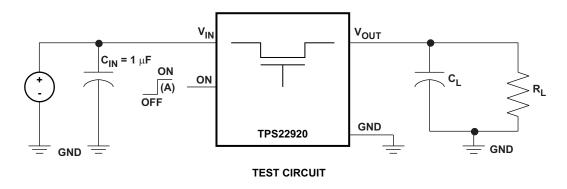
	PARAMETER	TEST CONDITION	MIN TYP	MAX	UNIT
t _{ON}	Turn-ON time	$R_L = 10 \Omega$, $C_L = 0.1 \mu F$, $V_{IN} = 3.6 V$	970		μs
t _{OFF}	Turn-OFF time	$R_L = 10 \Omega$, $C_L = 0.1 \mu F$, $V_{IN} = 3.6 V$	3		
t _r	VOUT Rise time	$R_L = 10 \Omega$, $C_L = 0.1 \mu F$, $V_{IN} = 3.6 V$	880		
t _f	VOUT Fall time	$R_L = 10 \Omega$, $C_L = 0.1 \mu F$, $V_{IN} = 3.6 V$	2		

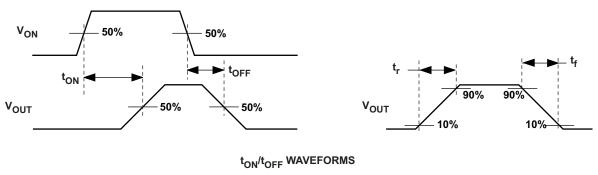
$V_{IN} = 0.9 \text{ V}, T_A = 25^{\circ}\text{C}$ (unless otherwise noted)

	PARAMETER	TEST CONDITION	MIN TYP MA	AX UNIT
t _{ON}	Turn-ON time	$R_L = 10 \Omega$, $C_L = 0.1 \mu F$, $V_{IN} = 0.9 V$	840	μs
t _{OFF}	Turn-OFF time	$R_L = 10 \Omega$, $C_L = 0.1 \mu F$, $V_{IN} = 0.9 V$	16	
t _r	VOUT Rise time	$R_L = 10 \Omega$, $C_L = 0.1 \mu F$, $V_{IN} = 0.9 V$	470	
t _f	VOUT Fall time	$R_L = 10 \Omega$, $C_L = 0.1 \mu F$, $V_{IN} = 0.9 V$	5	



PARAMETRIC MEASUREMENT INFORMATION





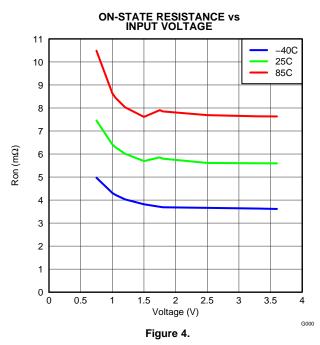
(A) Rise and fall times of the control signal is 100 ns.

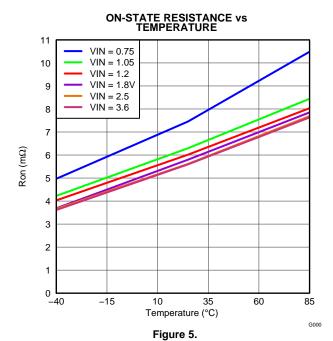
Figure 3. Test Circuit and $t_{\text{ON}}/t_{\text{OFF}}$ Waveforms

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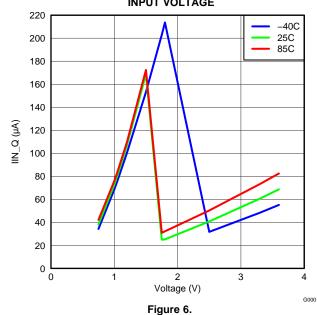


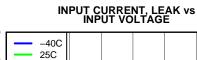
TYPICAL CHARACTERISTICS











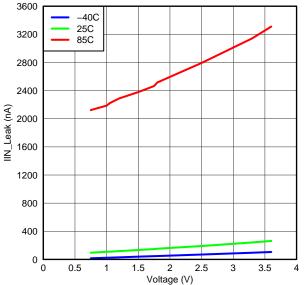
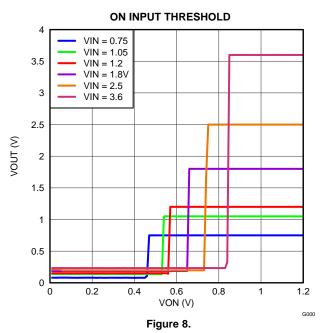


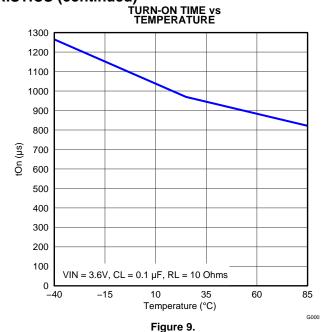
Figure 7.

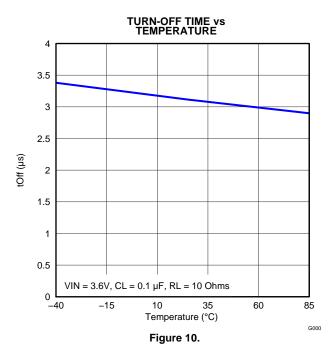
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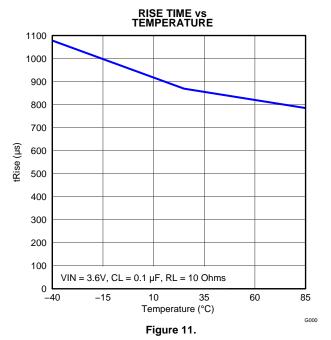


TYPICAL CHARACTERISTICS (continued)



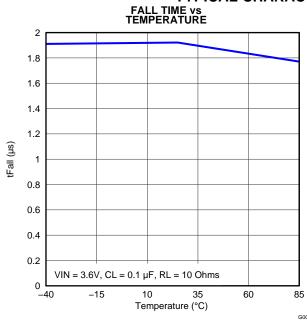












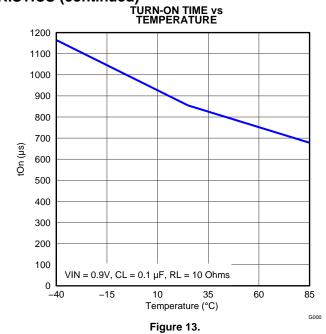


Figure 12.



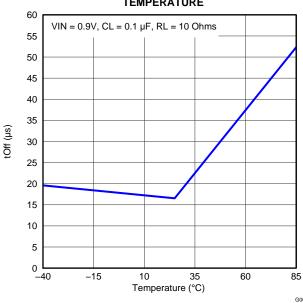


Figure 14.

RISE TIME vs TEMPERATURE

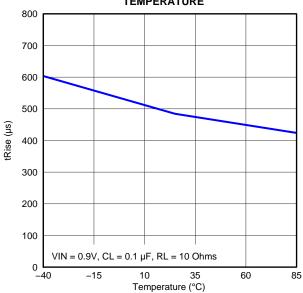


Figure 15.

-40C

25C

85C

3.5

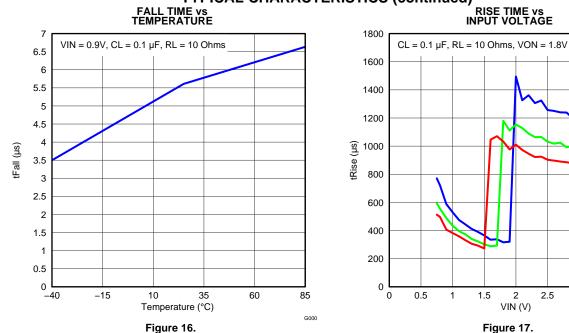
2.5

VIN (V)

3



TYPICAL CHARACTERISTICS (continued)



RISE TIME vs INPUT VOLTAGE

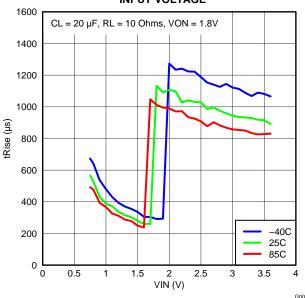
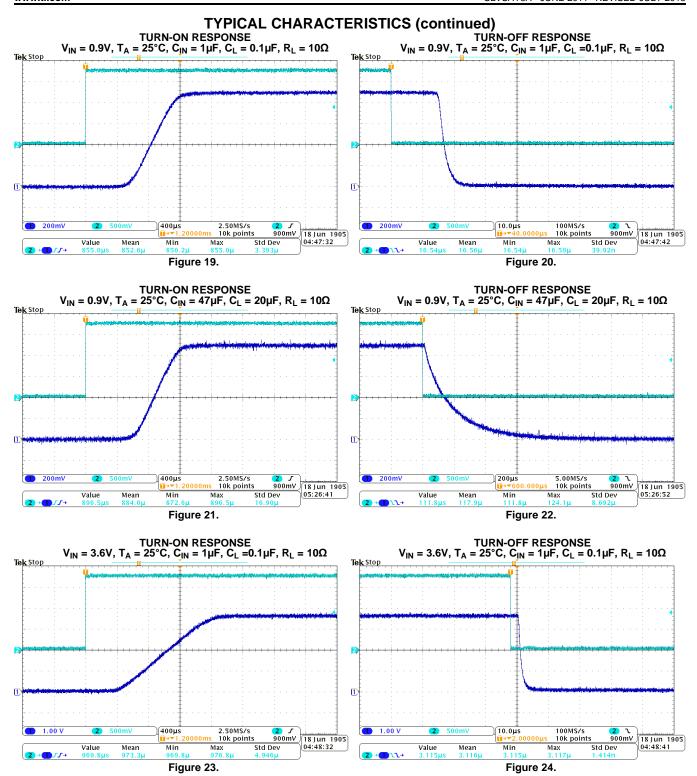


Figure 18.

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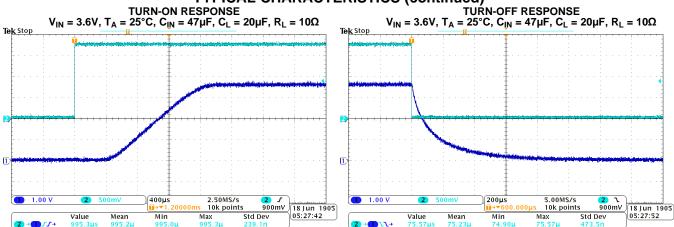


Figure 25.

Figure 26.



APPLICATION INFORMATION

ON/OFF CONTROL

The ON pin controls the state of the switch. Asserting ON high enables the switch. ON is active high and has a low threshold, making it capable of interfacing with low-voltage signals. The ON pin is compatible with standard GPIO logic threshold. It can be used with any microcontroller with 1.2-V, 1.8-V, 2.5-V or 3.3-V GPIOs.

INPUT CAPACITOR

To limit the voltage drop on the input supply caused by transient inrush currents when the switch turns on into a discharged load capacitor or short-circuit, a capacitor needs to be placed between V_{IN} and GND. A 1- μ F ceramic capacitor, C_{IN} , placed close to the pins is usually sufficient. Higher values of C_{IN} can be used to further reduce the voltage drop.

OUTPUT CAPACITOR

Due to the integral body diode in the NMOS switch, a C_{IN} greater than C_L is highly recommended. A C_L greater than C_{IN} can cause V_{OUT} to exceed VIN when the system supply is removed. This could result in current flow through the body diode from V_{OUT} to V_{IN} . A C_{IN} to C_L ratio of 10 to 1 is recommended for minimizing V_{IN} dip caused by inrush currents during startup.

OUTPUT PULL-DOWN

The output pulldown is active when the user is turning off the main pass FET. The pulldown discharges the output rail to approximately 10% of the rail, and then the output pulldown is automatically disconnected to optimize the shutdown current.

BOARD LAYOUT

For best performance, all traces should be as short as possible. To be most effective, the input and output capacitors should be placed close to the device to minimize the effects that parasitic trace inductances may have on normal operation. Using wide traces for V_{IN} , V_{OUT} , and GND helps minimize the parasitic electrical effects along with minimizing the case to ambient thermal impedance.

SLVSAY8A – JUNE 2011 – REVISED JULY 2013



REVISION HISTORY

Cr	hanges from Original (June 2011) to Revision A	Page
•	Updated swapped image issue.	8





17-Jul-2013

PACKAGING INFORMATION

Orderable Device	Status	Package Type	_	Pins	_	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Ma	rking Samples
	(1)		Drawing		Qty	(2)		(3)		(4/5)	
TPS22920YZPR	ACTIVE	DSBGA	YZP	8	3000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 85	6Z	Samples
TPS22920YZPRB	ACTIVE	DSBGA	YZP	8	3000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 85	6Z S	Samples
TPS22920YZPT	ACTIVE	DSBGA	YZP	8	250	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 85	6Z	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

- (3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

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PACKAGE OPTION ADDENDUM

17-Jul-2013

In no event shall TI's liabilit	ty arising out of such information exceed the total	purchase price of the TI part(s) at issue in this of	document sold by TI to Customer on an annual basis.

PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Air dimensions are nonlinia												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS22920YZPR	DSBGA	YZP	8	3000	180.0	8.4	1.02	2.02	0.63	4.0	8.0	Q1
TPS22920YZPRB	DSBGA	YZP	8	3000	180.0	8.4	1.02	2.02	0.63	4.0	8.0	Q1
TPS22920YZPT	DSBGA	YZP	8	250	180.0	8.4	1.02	2.02	0.63	4.0	8.0	Q1

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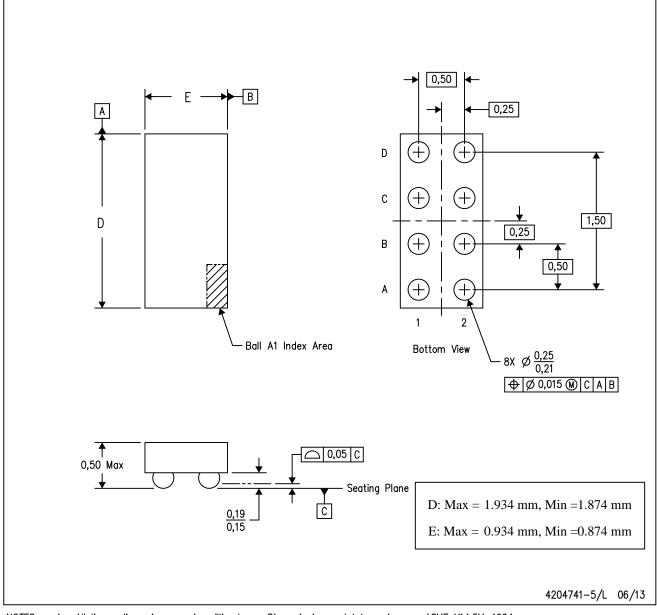


*All dimensions are nominal

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Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS22920YZPR	DSBGA	YZP	8	3000	182.0	182.0	17.0
TPS22920YZPRB	DSBGA	YZP	8	3000	182.0	182.0	17.0
TPS22920YZPT	DSBGA	YZP	8	250	182.0	182.0	17.0

YZP (R-XBGA-N8)

DIE-SIZE BALL GRID ARRAY



NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. NanoFree \mathbf{M} package configuration.

NanoFree is a trademark of Texas Instruments.



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Products Applications

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